

# DATA SHEET

## **74AHC1G14; 74AHCT1G14** Inverting Schmitt trigger

Product specification  
Supersedes data of 1999 Aug 05  
File under Integrated Circuits, IC06

2001 Feb 22

## Inverting Schmitt trigger

## 74AHC1G14; 74AHCT1G14

## FEATURES

- Symmetrical output impedance
- High noise immunity
- ESD protection:
  - HBM EIA/JESD22-A114-A exceeds 2000 V
  - MM EIA/JESD22-A115-A exceeds 200 V.
- Low power dissipation
- Balanced propagation delays
- Very small 5 pin package
- Output capability: standard.

## APPLICATIONS

- Wave and pulse shapers
- Astable multivibrators
- Monostable multivibrators.

## DESCRIPTION

The 74AHC1G/AHCT1G14 is a high-speed Si-gate CMOS device.

The 74AHC1G/AHCT1G14 provides the inverting buffer function with Schmitt-trigger action. These devices are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

## QUICK REFERENCE DATA

GND = 0 V;  $T_{amb} = 25\text{ }^{\circ}\text{C}$ ;  $t_r = t_f \leq 3.0\text{ ns}$ .

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			AHC1G	AHCT1G	
$t_{PHL}/t_{PLH}$	propagation delay A to Y	$C_L = 15\text{ pF}$ ; $V_{CC} = 5\text{ V}$	3.2	4.1	ns
$C_I$	input capacitance		1.5	1.5	pF
$C_{PD}$	power dissipation capacitance	$C_L = 15\text{ pF}$ ; $f = 1\text{ MHz}$ ; notes 1 and 2	12	13	pF

## Notes

1.  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).

$P_D = C_{PD} \times V_{CC}^2 \times f_i + (C_L \times V_{CC}^2 \times f_o)$  where:

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

$C_L$  = output load capacitance in pF;

$V_{CC}$  = supply voltage in Volts.

2. The condition is  $V_I = \text{GND to } V_{CC}$ .

## FUNCTION TABLE

See note 1.

INPUT	OUTPUT
A	Y
L	H
H	L

## Note

1. H = HIGH voltage level;  
L = LOW voltage level.

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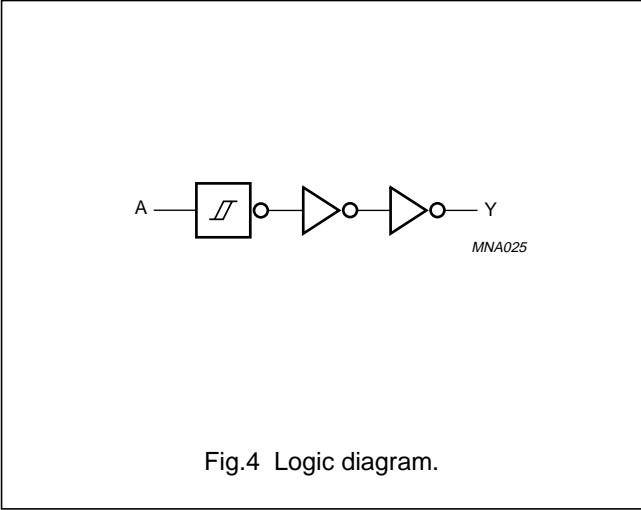
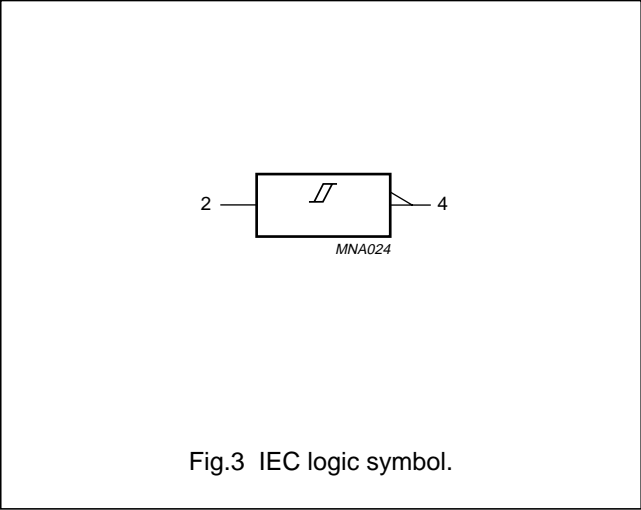
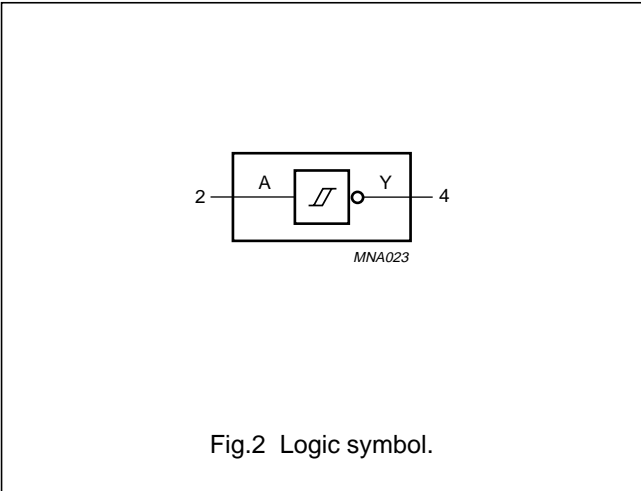
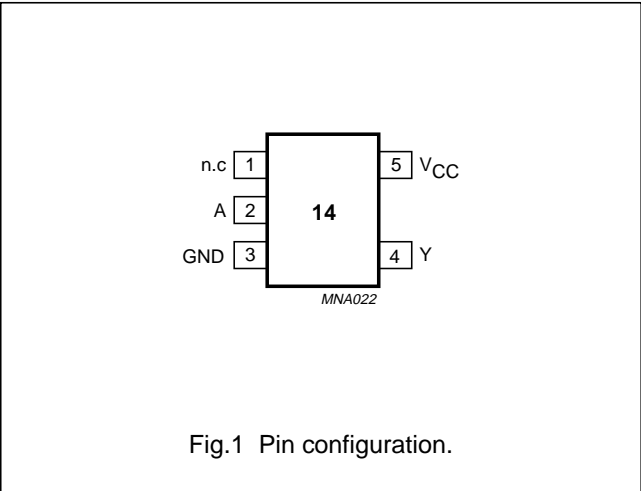
74AHC1G14; 74AHCT1G14

ORDERING INFORMATION

TYPE NUMBER	PACKAGES					
	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE	MARKING
74AHC1G14GW	−40 to +85 °C	5	SC-88A	plastic	SOT353	AF
74AHCT1G14GW	−40 to +85 °C	5	SC-88A	plastic	SOT353	CF

PINNING

PIN	SYMBOL	DESCRIPTION
1	n.c.	not connected
2	A	data input A
3	GND	ground (0 V)
4	Y	data output Y
5	V <sub>CC</sub>	supply voltage



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## RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	74AHC1G			74AHCT1G			UNIT
			MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
$V_{CC}$	supply voltage		2.0	5.0	5.5	4.5	5.0	5.5	V
$V_I$	input voltage		0	–	5.5	0	–	5.5	V
$V_O$	output voltage		0	–	$V_{CC}$	0	–	$V_{CC}$	V
$T_{amb}$	operating ambient temperature	see DC and AC characteristics per device	–40	+25	+85	–40	+25	+85	°C

## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CC}$	supply voltage		–0.5	+7.0	V
$V_I$	input voltage		–0.5	+7.0	V
$I_{IK}$	input diode current	$V_I < -0.5$ V	–	–20	mA
$I_{OK}$	output diode current	$V_O < -0.5$ V or $V_O > V_{CC} + 0.5$ V; note 1	–	±20	mA
$I_O$	output source or sink current	$-0.5$ V < $V_O$ < $V_{CC} + 0.5$ V	–	±25	mA
$I_{CC}$	$V_{CC}$ or GND current		–	±75	mA
$T_{stg}$	storage temperature		–65	+150	°C
$P_D$	power dissipation per package	for temperature range from –40 to +85 °C; note 2	–	200	mW

## Notes

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. Above 55 °C the value of  $P_D$  derates linearly with 2.5 mW/K.

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## DC CHARACTERISTICS

## Family 74AHC1G

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		T <sub>amb</sub> (°C)					UNIT
		OTHER	V <sub>CC</sub> (V)	25			–40 to +85		
				MIN.	TYP.	MAX.	MIN.	MAX.	
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = –50 μA	2.0	1.9	2.0	–	1.9	–	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = –50 μA	3.0	2.9	3.0	–	2.9	–	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = –50 μA	4.5	4.4	4.5	–	4.4	–	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = –4.0 mA	3.0	2.58	–	–	2.48	–	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = –8.0 mA	4.5	3.94	–	–	3.8	–	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = 50 μA	2.0	–	0	0.1	–	0.1	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = 50 μA	3.0	–	0	0.1	–	0.1	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = 50 μA	4.5	–	0	0.1	–	0.1	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = 4.0 mA	3.0	–	–	0.36	–	0.44	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = 8.0 mA	4.5	–	–	0.36	–	0.44	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND	5.5	–	–	0.1	–	1.0	μA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0	5.5	–	–	1.0	–	10	μA
C <sub>I</sub>	input capacitance			–	1.5	10	–	10	pF

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## Family 74AHCT1G

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		T <sub>amb</sub> (°C)					UNIT
		OTHER	V <sub>CC</sub> (V)	25			−40 to +85		
				MIN.	TYP.	MAX.	MIN.	MAX.	
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = −50 μA	4.5	4.4	4.5	—	4.4	—	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = −8.0 mA	4.5	3.94	—	—	3.8	—	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = 50 μA	4.5	—	0	0.1	—	0.1	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = 8.0 mA	4.5	—	—	0.36	—	0.44	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>	5.5	—	—	0.1	—	1.0	μA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0	5.5	—	—	1.0	—	10	μA
ΔI <sub>CC</sub>	additional quiescent supply current per input pin	V <sub>I</sub> = 3.4 V; other inputs at V <sub>CC</sub> or GND; I <sub>O</sub> = 0	5.5	—	—	1.35	—	1.5	mA
C <sub>I</sub>	input capacitance			—	1.5	10	—	10	pF

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## TRANSFER CHARACTERISTICS

## Type 74AHC1G14

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		T <sub>amb</sub> (°C)					UNIT
		OTHER	V <sub>CC</sub> (V)	25			–40 to +85		
				MIN.	TYP.	MAX.	MIN.	MAX.	
V <sub>T+</sub>	positive-going threshold	see Figs 7 and 8	3.0	–	–	2.2	–	2.2	V
			4.5	–	–	3.15	–	3.15	V
			5.5	–	–	3.85	–	3.85	V
V <sub>T–</sub>	negative-going threshold	see Figs 7 and 8	3.0	0.9	–	–	0.9	–	V
			4.5	1.35	–	–	1.35	–	V
			5.5	1.65	–	–	1.65	–	V
V <sub>H</sub>	hysteresis (V <sub>T+</sub> – V <sub>T–</sub> )	see Figs 7 and 8	3.0	0.3	–	1.2	0.3	1.2	V
			4.5	0.4	–	1.4	0.4	1.4	V
			5.5	0.5	–	1.6	0.5	1.6	V

## Type 74AHCT1G14

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		T <sub>amb</sub> (°C)					UNIT
		WAVEFORMS	V <sub>CC</sub> (V)	25			–40 to +85		
				MIN.	TYP.	MAX.	MIN.	MAX.	
V <sub>T+</sub>	positive-going threshold	see Figs 7 and 8	4.5	–	–	2.0	–	2.0	V
			5.5	–	–	2.0	–	2.0	V
V <sub>T–</sub>	negative-going threshold	see Figs 7 and 8	4.5	0.5	–	–	0.5	–	V
			5.5	0.6	–	–	0.6	–	V
V <sub>H</sub>	hysteresis (V <sub>T+</sub> – V <sub>T–</sub> )	see Figs 7 and 8	4.5	0.4	–	1.4	0.4	1.4	V
			5.5	0.4	–	1.6	0.4	1.6	V

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## AC CHARACTERISTICS

## Type 74AHC1G14

GND = 0 V;  $t_r = t_f \leq 3.0$  ns.

SYMBOL	PARAMETER	TEST CONDITIONS		T <sub>amb</sub> (°C)					UNIT
		WAVEFORMS	C <sub>L</sub>	25			−40 to +85		
				MIN.	TYP.	MAX.	MIN.	MAX.	
V <sub>CC</sub> = 3.0 to 3.6V; note 1									
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay A to Y	see Figs 5 and 6	15 pF	—	4.2	12.8	1.0	15.0	ns
			50 pF	—	6.0	16.3	1.0	18.5	ns
V <sub>CC</sub> = 4.5 to 5.5 V; note 2									
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay A to Y	see Figs 5 and 6	15 pF	—	3.2	8.6	1.0	10.0	ns
			50 pF	—	4.6	10.6	1.0	12.0	ns

## Notes

1. Typical values are measured at V<sub>CC</sub> = 3.3 V.
2. Typical values are measured at V<sub>CC</sub> = 5.0 V.

## Type 74AHCT1G14

GND = 0 V;  $t_r = t_f \leq 3.0$  ns.

SYMBOL	PARAMETER	TEST CONDITIONS		T <sub>amb</sub> (°C)					UNIT
		WAVEFORMS	C <sub>L</sub>	25			–40 to +85		
				MIN.	TYP.	MAX.	MIN.	MAX.	
V <sub>CC</sub> = 4.5 to 5.5 V; note 1									
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay A to Y	see Figs 5 and 6	15 pF	–	4.1	7.0	1.0	8.0	ns
			50 pF	–	5.9	8.5	1.0	10.0	ns

## Note

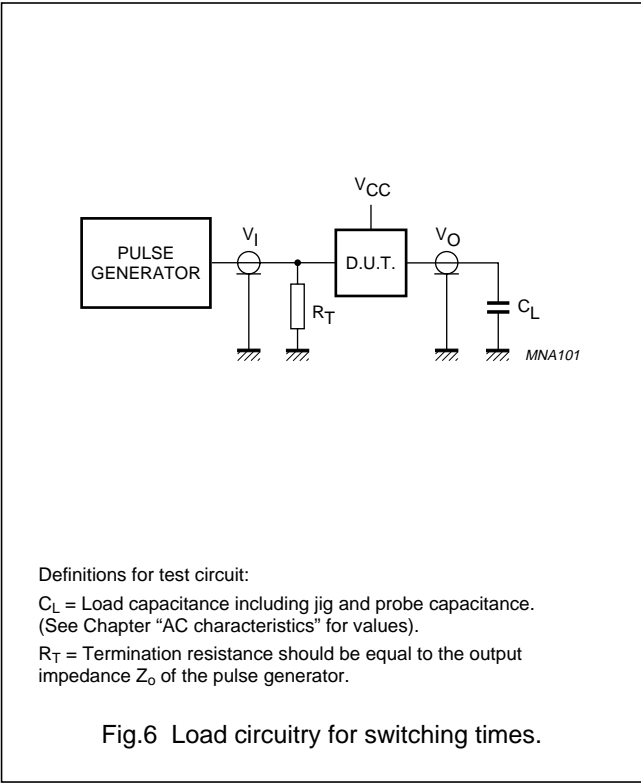
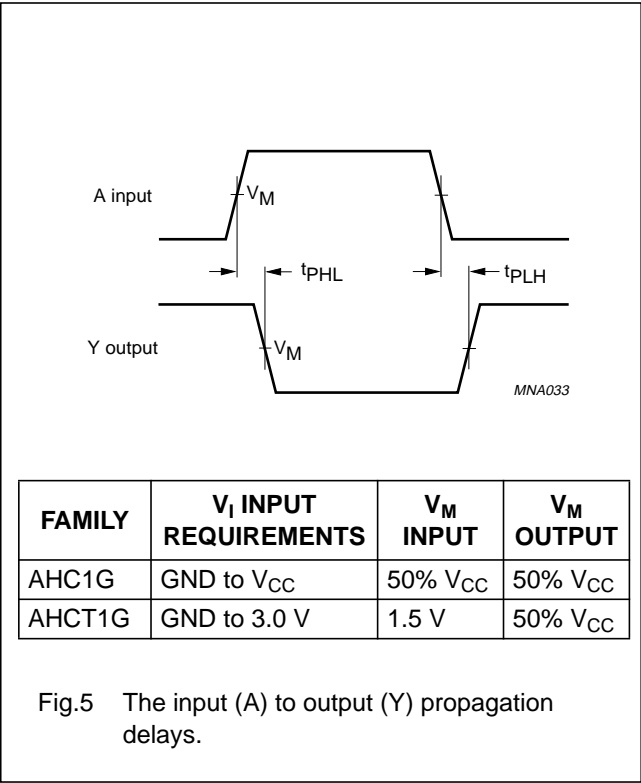
1. Typical values are measured at V<sub>CC</sub> = 5 V.



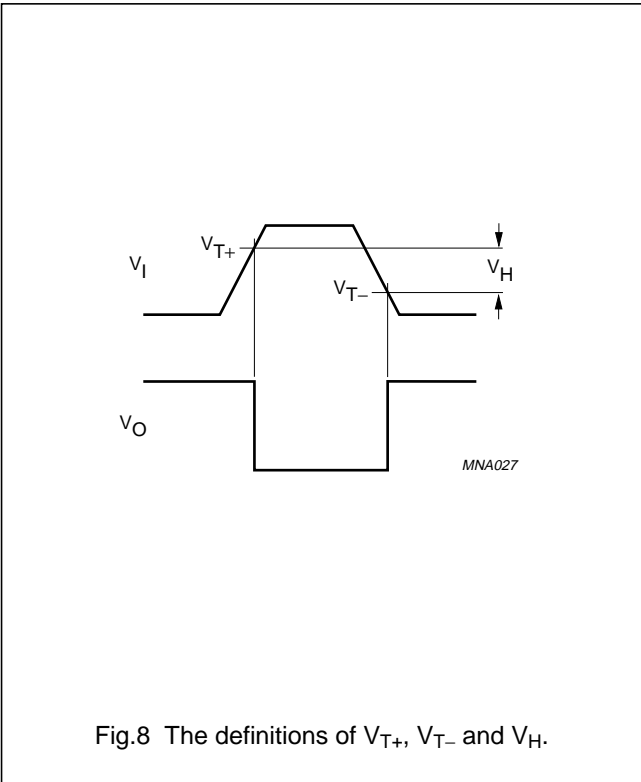
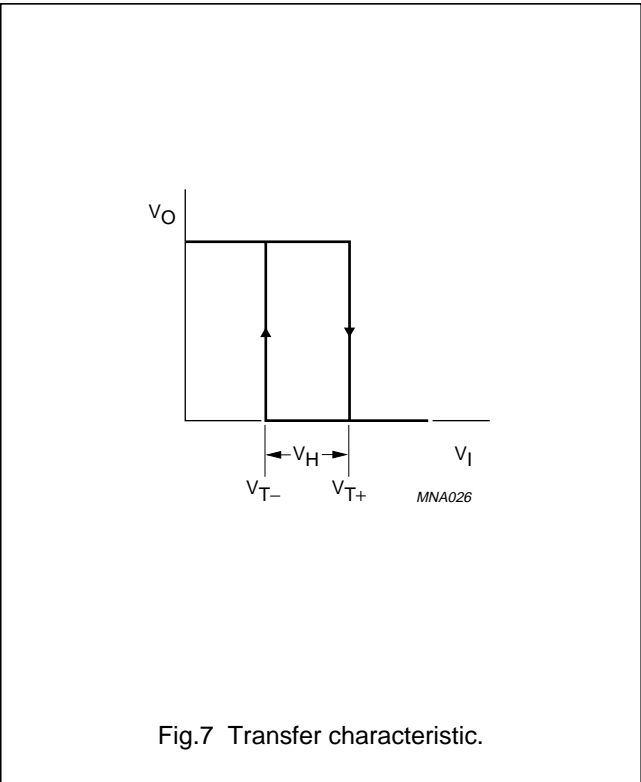
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AC WAVEFORMS



TRANSFER CHARACTERISTIC WAVEFORMS



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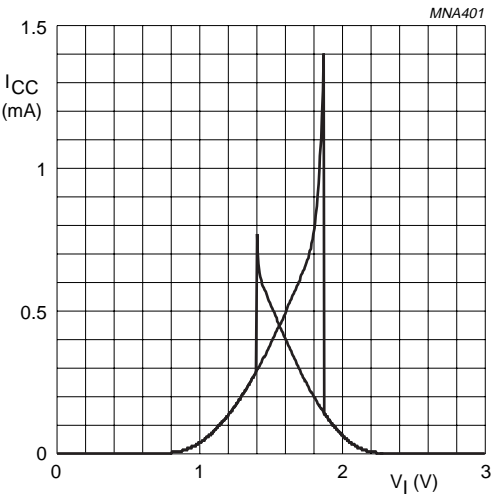


Fig.9 Typical AHC1G14 transfer characteristics;  $V_{CC} = 3.0$  V.

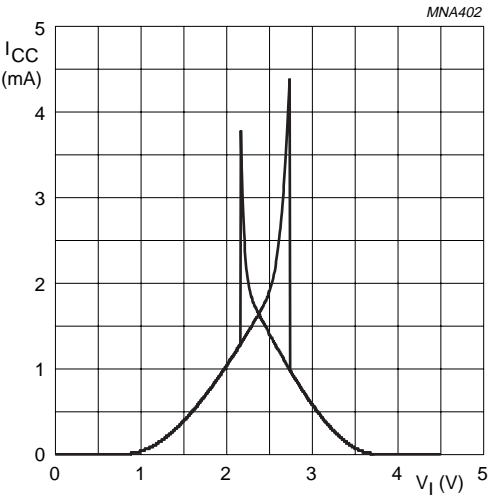


Fig.10 Typical AHC1G14 transfer characteristics;  $V_{CC} = 4.5$  V.

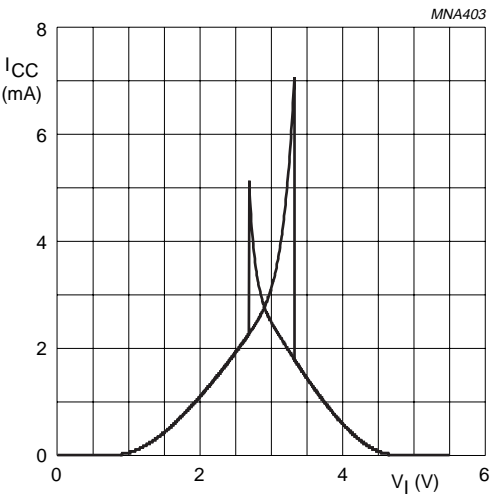


Fig.11 Typical AHC1G14 transfer characteristics;  $V_{CC} = 5.5$  V.

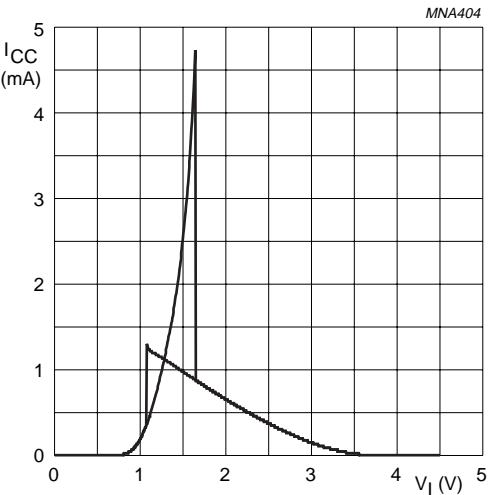


Fig.12 Typical AHCT1G14 transfer characteristics;  $V_{CC} = 4.5$  V.

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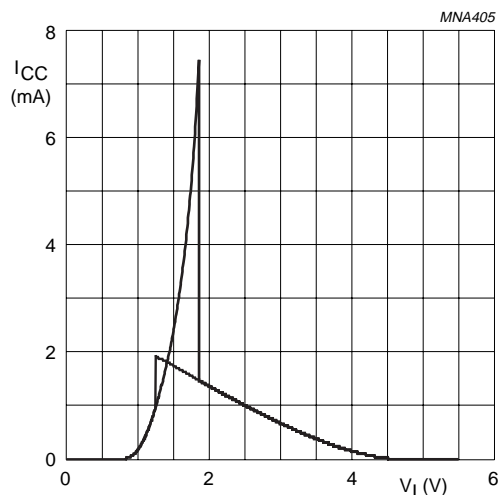


Fig.13 Typical AHCT1G14 transfer characteristics;  
V<sub>CC</sub> = 5.5 V.

APPLICATION INFORMATION

The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

$P_{ad} = f_i \times (t_r \times I_{CC(AV)} + t_f \times I_{CC(AV)}) \times V_{CC}$  where:

P<sub>ad</sub> = additional power dissipation (μW);

f<sub>i</sub> = input frequency (MHz);

t<sub>r</sub> = input rise time (ns); 10% to 90%;

t<sub>f</sub> = input fall time (ns); 90% to 10%;

I<sub>CC(AV)</sub> = average additional supply current (μA).

Average I<sub>CC</sub> differs with positive or negative input transitions, as shown in Figs 14 and 15.

For AHC1G/AHCT1G14 used in relaxation oscillator circuit, see Fig.16.

Note to the application information:

- 1. All values given are typical unless otherwise specified.

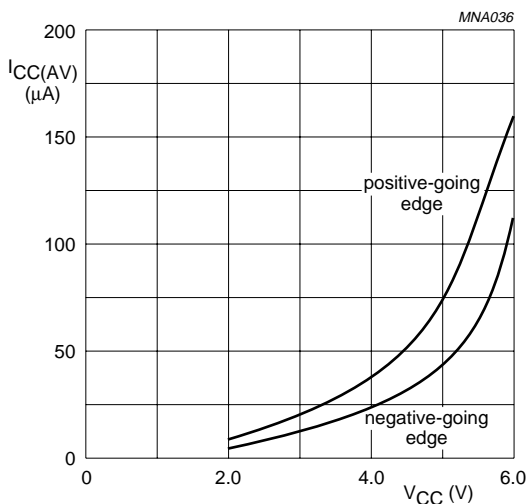


Fig.14 Average I<sub>CC</sub> for AHC1G Schmitt-trigger devices; linear change of V<sub>I</sub> between 0.1V<sub>CC</sub> to 0.9V<sub>CC</sub>.

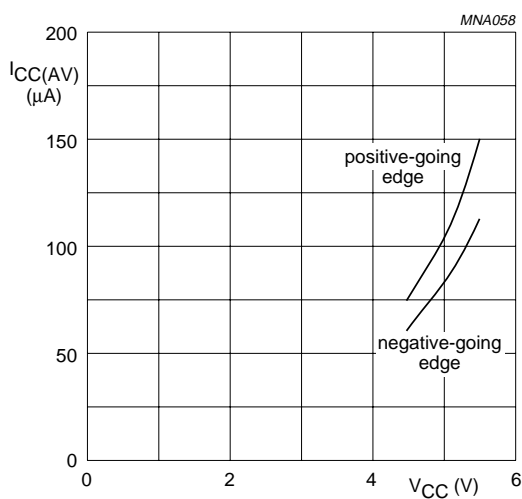
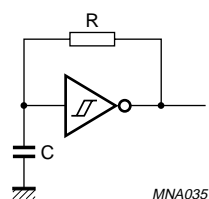


Fig.15 Average I<sub>CC</sub> for AHCT1G Schmitt-trigger devices; linear change of V<sub>I</sub> between 0.1V<sub>CC</sub> to 0.9V<sub>CC</sub>.

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For AHC1G:  $f = \frac{1}{T} \approx \frac{1}{0.55 \times RC}$

For AHCT1G:  $f = \frac{1}{T} \approx \frac{1}{0.60 \times RC}$

Fig.16 Relaxation oscillator using the AHC1G/AHCT1G14.

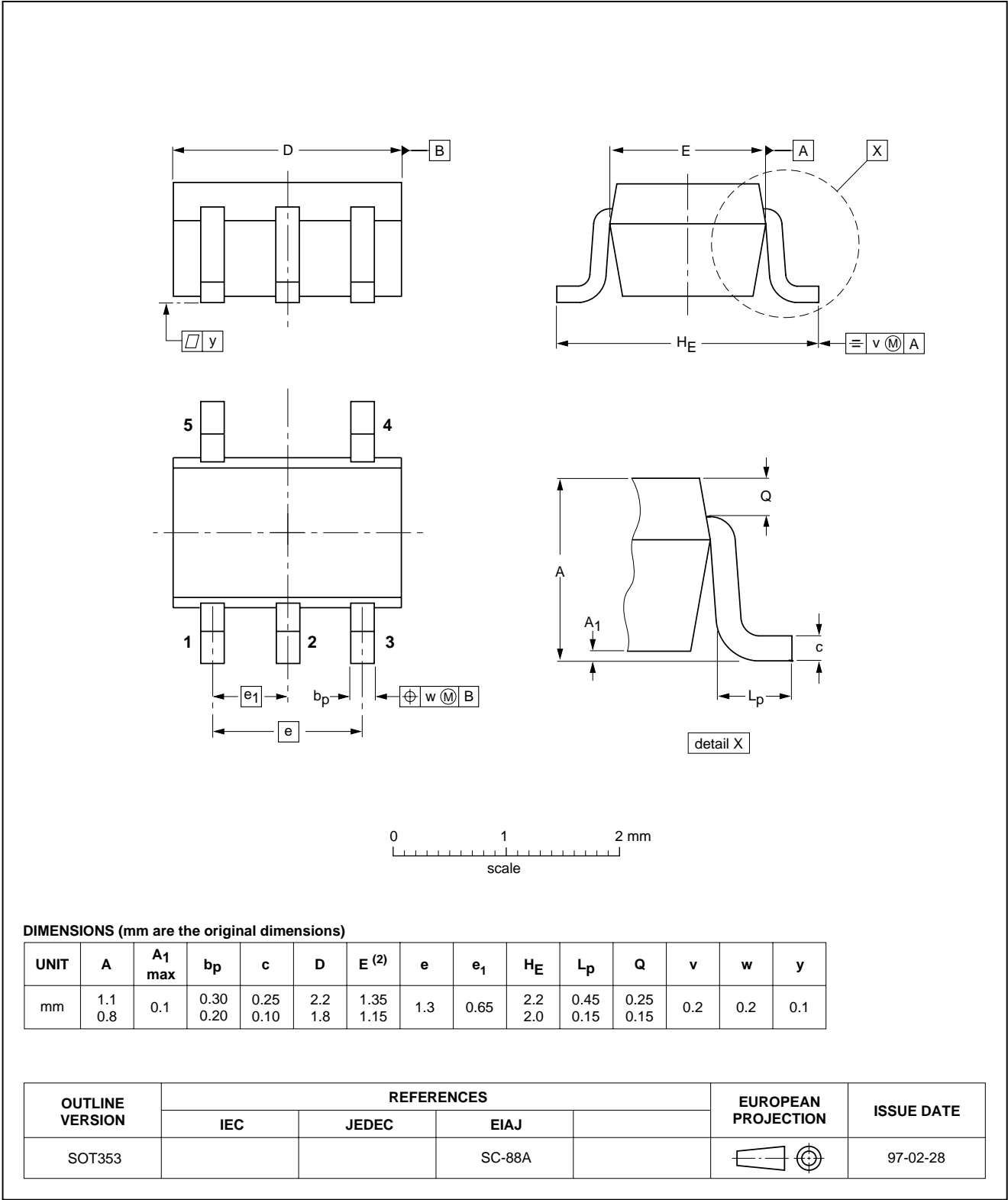
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PACKAGE OUTLINE

Plastic surface mounted package; 5 leads

SOT353



## Inverting Schmitt trigger

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### SOLDERING

#### Introduction to soldering surface mount packages

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"Data Handbook IC26; Integrated Circuit Packages"* (document order number 9398 652 90011).

There is no soldering method that is ideal for all surface mount IC packages. Wave soldering can still be used for certain surface mount ICs, but it is not suitable for fine pitch SMDs. In these situations reflow soldering is recommended.

#### Reflow soldering

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, convection or convection/infrared heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 to 250 °C. The top-surface temperature of the packages should preferably be kept below 220 °C for thick/large packages, and below 235 °C for small/thin packages.

#### Wave soldering

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
  - larger than or equal to 1.27 mm, the footprint longitudinal axis is **preferred** to be parallel to the transport direction of the printed-circuit board;
  - smaller than 1.27 mm, the footprint longitudinal axis **must** be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

- For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time is 4 seconds at 250 °C.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

#### Manual soldering

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C.

When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

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## Suitability of surface mount IC packages for wave and reflow soldering methods

PACKAGE	SOLDERING METHOD	
	WAVE	REFLOW <sup>(1)</sup>
BGA, HBGA, LFBGA, SQFP, TFBGA	not suitable	suitable
HBCC, HLQFP, HSQFP, HSOP, HTQFP, HTSSOP, HVQFN, SMS	not suitable <sup>(2)</sup>	suitable
PLCC <sup>(3)</sup> , SO, SOJ	suitable	suitable
LQFP, QFP, TQFP	not recommended <sup>(3)(4)</sup>	suitable
SSOP, TSSOP, VSO	not recommended <sup>(5)</sup>	suitable

## Notes

1. All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the *"Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods"*.
2. These packages are not suitable for wave soldering as a solder joint between the printed-circuit board and heatsink (at bottom version) can not be achieved, and as solder may stick to the heatsink (on top version).
3. If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
4. Wave soldering is only suitable for LQFP, TQFP and QFP packages with a pitch (e) equal to or larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
5. Wave soldering is only suitable for SSOP and TSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.

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## DATA SHEET STATUS

DATA SHEET STATUS	PRODUCT STATUS	DEFINITIONS <sup>(1)</sup>
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

## Note

1. Please consult the most recently issued data sheet before initiating or completing a design.

## DEFINITIONS

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

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Inverting Schmitt trigger

74AHC1G14; 74AHCT1G14

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**NOTES**

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**Inverting Schmitt trigger****74AHC1G14; 74AHCT1G14**

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Inverting Schmitt trigger

74AHC1G14; 74AHCT1G14

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# Philips Semiconductors – a worldwide company

**Argentina:** see South America

**Australia:** 3 Figtree Drive, HOMEBUSH, NSW 2140,  
Tel. +61 2 9704 8141, Fax. +61 2 9704 8139

**Austria:** Computerstr. 6, A-1101 WIEN, P.O. Box 213,  
Tel. +43 1 60 101 1248, Fax. +43 1 60 101 1210

**Belarus:** Hotel Minsk Business Center, Bld. 3, r. 1211, Volodarski Str. 6,  
220050 MINSK, Tel. +375 172 20 0733, Fax. +375 172 20 0773

**Belgium:** see The Netherlands

**Brazil:** see South America

**Bulgaria:** Philips Bulgaria Ltd., Energoprojekt, 15th floor,  
51 James Bourchier Blvd., 1407 SOFIA,  
Tel. +359 2 68 9211, Fax. +359 2 68 9102

**Canada:** PHILIPS SEMICONDUCTORS/COMPONENTS,  
Tel. +1 800 234 7381, Fax. +1 800 943 0087

**China/Hong Kong:** 501 Hong Kong Industrial Technology Centre,  
72 Tat Chee Avenue, Kowloon Tong, HONG KONG,  
Tel. +852 2319 7888, Fax. +852 2319 7700

**Colombia:** see South America

**Czech Republic:** see Austria

**Denmark:** Sydhavnsgade 23, 1780 COPENHAGEN V,  
Tel. +45 33 29 3333, Fax. +45 33 29 3905

**Finland:** Sinikalliontie 3, FIN-02630 ESPOO,  
Tel. +358 9 615 800, Fax. +358 9 6158 0920

**France:** 51 Rue Carnot, BP317, 92156 SURESNES Cedex,  
Tel. +33 1 4099 6161, Fax. +33 1 4099 6427

**Germany:** Hammerbrookstraße 69, D-20097 HAMBURG,  
Tel. +49 40 2353 60, Fax. +49 40 2353 6300

**Hungary:** Philips Hungary Ltd., H-1119 Budapest, Fehervari ut 84/A,  
Tel. +36 1 382 1700, Fax. +36 1 382 1800

**India:** Philips INDIA Ltd, Band Box Building, 2nd floor,  
254-D, Dr. Annie Besant Road, Worli, MUMBAI 400 025,  
Tel. +91 22 493 8541, Fax. +91 22 493 0966

**Indonesia:** PT Philips Development Corporation, Semiconductors Division,  
Gedung Philips, Jl. Buncit Raya Kav.99-100, JAKARTA 12510,  
Tel. +62 21 794 0040 ext. 2501, Fax. +62 21 794 0080

**Ireland:** Newstead, Clonskeagh, DUBLIN 14,  
Tel. +353 1 7640 000, Fax. +353 1 7640 200

**Israel:** RAPAC Electronics, 7 Kehilat Saloniki St, PO Box 18053,  
TEL AVIV 61180, Tel. +972 3 645 0444, Fax. +972 3 649 1007

**Italy:** PHILIPS SEMICONDUCTORS, Via Casati, 23 - 20052 MONZA (MI),  
Tel. +39 039 203 6838, Fax +39 039 203 6800

**Japan:** Philips Bldg 13-37, Kohnan 2-chome, Minato-ku,  
TOKYO 108-8507, Tel. +81 3 3740 5130, Fax. +81 3 3740 5057

**Korea:** Philips House, 260-199 Itaewon-dong, Yongsan-ku, SEOUL,  
Tel. +82 2 709 1412, Fax. +82 2 709 1415

**Malaysia:** No. 76 Jalan Universiti, 46200 PETALING JAYA, SELANGOR,  
Tel. +60 3 750 5214, Fax. +60 3 757 4880

**Mexico:** 5900 Gateway East, Suite 200, EL PASO, TEXAS 79905,  
Tel. +9-5 800 234 7381, Fax +9-5 800 943 0087

**Middle East:** see Italy

**Netherlands:** Postbus 90050, 5600 PB EINDHOVEN, Bldg. VB,  
Tel. +31 40 27 82785, Fax. +31 40 27 88399

**New Zealand:** 2 Wagener Place, C.P.O. Box 1041, AUCKLAND,  
Tel. +64 9 849 4160, Fax. +64 9 849 7811

**Norway:** Box 1, Manglerud 0612, OSLO,  
Tel. +47 22 74 8000, Fax. +47 22 74 8341

**Pakistan:** see Singapore

**Philippines:** Philips Semiconductors Philippines Inc.,  
106 Valero St. Salcedo Village, P.O. Box 2108 MCC, MAKATI,  
Metro MANILA, Tel. +63 2 816 6380, Fax. +63 2 817 3474

**Poland:** Al.Jerozolimskie 195 B, 02-222 WARSAW,  
Tel. +48 22 5710 000, Fax. +48 22 5710 001

**Portugal:** see Spain

**Romania:** see Italy

**Russia:** Philips Russia, Ul. Usatcheva 35A, 119048 MOSCOW,  
Tel. +7 095 755 6918, Fax. +7 095 755 6919

**Singapore:** Lorong 1, Toa Payoh, SINGAPORE 319762,  
Tel. +65 350 2538, Fax. +65 251 6500

**Slovakia:** see Austria

**Slovenia:** see Italy

**South Africa:** S.A. PHILIPS Pty Ltd., 195-215 Main Road Martindale,  
2092 JOHANNESBURG, P.O. Box 58088 Newville 2114,  
Tel. +27 11 471 5401, Fax. +27 11 471 5398

**South America:** Al. Vicente Pinzon, 173, 6th floor,  
04547-130 SÃO PAULO, SP, Brazil,  
Tel. +55 11 821 2333, Fax. +55 11 821 2382

**Spain:** Balmes 22, 08007 BARCELONA,  
Tel. +34 93 301 6312, Fax. +34 93 301 4107

**Sweden:** Kottbygatan 7, Akalla, S-16485 STOCKHOLM,  
Tel. +46 8 5985 2000, Fax. +46 8 5985 2745

**Switzerland:** Allmendstrasse 140, CH-8027 ZÜRICH,  
Tel. +41 1 488 2741 Fax. +41 1 488 3263

**Taiwan:** Philips Semiconductors, 5F, No. 96, Chien Kuo N. Rd., Sec. 1,  
TAIPEI, Taiwan Tel. +886 2 2134 2451, Fax. +886 2 2134 2874

**Thailand:** PHILIPS ELECTRONICS (THAILAND) Ltd.,  
60/14 MOO 11, Bangna Trad Road KM. 3, Bagna, BANGKOK 10260,  
Tel. +66 2 361 7910, Fax. +66 2 398 3447

**Turkey:** Yukari Dudullu, Org. San. Blg., 2.Cad. Nr. 28 81260 Umraniye,  
ISTANBUL, Tel. +90 216 522 1500, Fax. +90 216 522 1813

**Ukraine:** PHILIPS UKRAINE, 4 Patrice Lumumba str., Building B, Floor 7,  
252042 KIEV, Tel. +380 44 264 2776, Fax. +380 44 268 0461

**United Kingdom:** Philips Semiconductors Ltd., 276 Bath Road, Hayes,  
MIDDLESEX UB3 5BX, Tel. +44 208 730 5000, Fax. +44 208 754 8421

**United States:** 811 East Arques Avenue, SUNNYVALE, CA 94088-3409,  
Tel. +1 800 234 7381, Fax. +1 800 943 0087

**Uruguay:** see South America

**Vietnam:** see Singapore

**Yugoslavia:** PHILIPS, Trg N. Pasica 5/v, 11000 BEOGRAD,  
Tel. +381 11 3341 299, Fax. +381 11 3342 553

**For all other countries apply to:** Philips Semiconductors,  
Marketing Communications, Building BE-p, P.O. Box 218, 5600 MD EINDHOVEN,  
The Netherlands, Fax. +31 40 27 24825

**Internet:** <http://www.semiconductors.philips.com>

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